

## Refine Search

### Search Results -

Terms	Documents
L11 and (nitride near8 (aperture or hole or via or opening)).clm.	2

Database:

US Pre-Grant Publication Full-Text Database  
 US Patents Full-Text Database  
 US OCR Full-Text Database  
 EPO Abstracts Database  
 JPO Abstracts Database  
 Derwent World Patents Index  
 IBM Technical Disclosure Bulletins

Search:

L13





### Search History

DATE: Thursday, May 18, 2006    [Printable Copy](#)    [Create Case](#)

<u>Set</u> <u>Name</u> side by side	<u>Query</u>	<u>Hit</u> <u>Count</u>	<u>Set</u> <u>Name</u> result set
	<i>DB=PGPB,USPT,USOC,EPAB,JPAB,DWPI,TDBD; PLUR=YES; OP=ADJ</i>		
<u>L13</u>	L11 and (nitride near8 (aperture or hole or via or opening)).clm.	2	<u>L13</u>
<u>L12</u>	L11 and (nitride near8 (aperture or hole or via or opening))	4	<u>L12</u>
<u>L11</u>	L2 and (first near2 electrode same nitride same second near2 electrode)	31	<u>L11</u>
<u>L10</u>	L9 and (nitride near8 electrode)	11	<u>L10</u>
<u>L9</u>	L8 and L1	66	<u>L9</u>
<u>L8</u>	"Tomohiko".inv.	12525	<u>L8</u>
<u>L7</u>	L6 and L1	0	<u>L7</u>
<u>L6</u>	"Takumori".inv.	70	<u>L6</u>
<u>L5</u>	"Takumori" near3 "Iki"	0	<u>L5</u>
<u>L4</u>	Takumori near3 Iki	0	<u>L4</u>
<u>L3</u>	L2 and (nitride near8 (aperture or hole or via or opening))	59	<u>L3</u>
<u>L2</u>	L1 and (electrode near7 (top or above or bottom or underneath or over) near8 nitride)	265	<u>L2</u>

L1 ((thin film transistor)or TFT) same capacit\$

18922 L1

END OF SEARCH HISTORY